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- No Frequency Compensation Required
- Low Power Consumption
- **Short-Circuit Protection**
- **Offset-Voltage Null Capability**
- Wide Common-Mode and Differential **Voltage Ranges**
- No Latch-Up
- Designed to Be Interchangeable With Fairchild µA747C and µA747M

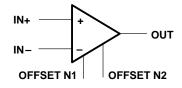
#### description

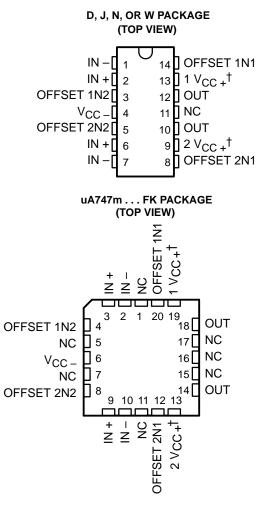
The uA747 is a dual general-purpose operational amplifier featuring offset-voltage null capability. Each half is electrically similar to uA741.

The high common-mode input voltage range and the absence of latch-up make this amplifier ideal for voltage-follower applications. The device is short-circuit protected and the internal frequency compensation ensures stability without external components. A low-value potentiometer may be connected between the offset null inputs to null out the offset voltage as shown in Figure 2.

The uA747C is characterized for operation from 0°C to 70°C; the uA747M is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to  $125^{\circ}$ C.

#### symbol (each amplifier)





NC - No internal connection

<sup>+</sup> The two positive supply terminals (1 V<sub>CC +</sub> and 2 V<sub>CC +</sub>) are connected together internally.

_	AVAILABLE OF HONS										
Γ			PACKAGE								
				20-PIN							
	TA	V <sub>IO</sub> Max AT 25°C	SMALL OUTLINE (D)	CERAMIC DIP (J)	PLASTIC DIP (N)	FLAT PACK (W)	CHIP CARRIER (FK)				
Γ	0°C										
	to 70°C	6 mV	uA747CD	—	uA747CN	—	—				
ſ	–55°C										
	to 125°C	5 mV	_	uA747MJ	—	uA747MW	uA747MFK				

AVAILABLE OPTIONS

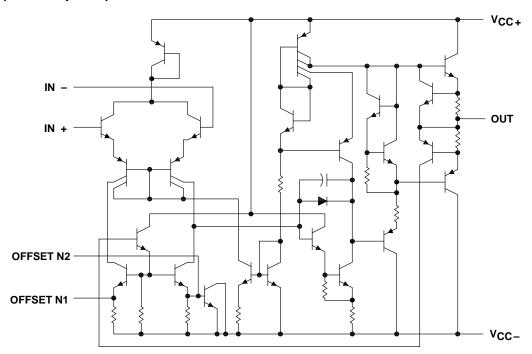
The D package is available taped and reeled. Add the suffix R to the device type, (i.e., uA747CDR).

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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### schematic (each amplifier)



### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		uA747C	uA747M	UNIT				
Supply voltage, V <sub>CC+</sub> (see Note 1)		18	22	V				
Supply voltage, V <sub>CC</sub> (see Note 1)		-18	-22	V				
Differential input voltage (see Note 2)		±30	±30	0 V				
Input voltage any input (see Notes 1 and 3)		±15	±15 ±15					
Voltage between any offset null terminal (N1/N2) and $V_{\mbox{CC}-}$		±0.5	±0.5 ±0.5					
Duration of output short circuit (see Note 4)		unlimited	unlimited					
Continuous total dissipation		See Diss	ble					
Operating free-air temperature range		0 to 70	0 to 70 -55 to 125					
Storage temperature range		-65 to 150	-65 to 150	°C				
Case temperature for 60 seconds	FK package		260	°C				
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J or W package		300	°C				
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or N package	260		°C				

NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V<sub>CC +</sub> and V<sub>CC -</sub>.

2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.

3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.

4. The output may be shorted to ground or either power supply. For the uA747M only, the unlimited duration of the short circuit applies at (or below) 125°C case temperature or 75°C free-air temperature.

#### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T <sub>A</sub>	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING				
D	800 mW	7.6 mW/°C	45°C	608 mW	_				
FK	800 mW	11.0 mW/°C	77°C	800 mW	275 mW				
J	800 mW	11.0 mW/°C	77°C	800 mW	275 mW				
Ν	800 mW	9.2 mW/°C	63°C	736 mW	—				
W	800 mW	8.0 mW/°C	50°C	640 mW	200 mW				



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	DADAMETED		<b>-</b> T	uA747C			uA747M				
PARAMETER		TEST CONDITIONS <sup>†</sup>	TA±	MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
Mar Innesta	Input offset voltage	V <sub>O</sub> = 0	25°C		1	6		1	5	mV	
VIO			Full range			7.5			6		
$\Delta V$ IO(adj)	Offset voltage adjust range		25°C		±15			±15		mV	
110	Input offset current		25°C		20	200		20	200	nA	
U	input onset current		Full range			300			500		
lun.	Input bias current		25°C		80	500		80	500	nA	
IB	input bias current		Full range			800			1500		
Vien	Common-mode		25°C	±12	±13		±12	±13		v	
VICR	input voltage range		Full range	±12			±12				
		RL= 10 kΩ	25°C	24	28		24	28		V	
	Maximum peak-to-peak	$R_L \ge 10 \ k\Omega$	Full range	24			24				
VO(PP)	output voltage swing	$R_L = 2 k\Omega$	25°C	20	26		20	26			
		$R_L \ge 2 k\Omega$	Full range	20			20				
٨	Large-signal differential	$R_L \ge 2 k\Omega$ ,	25°C	25	200		50	200		Mart	
AVD	voltage amplification	$V_{O} = \pm 10 V$	Full range	15			25			V/mV	
r <sub>i</sub>	Input resistance		25°C	0.3	2		0.3*	2		MΩ	
r <sub>o</sub>	Output resistance	See Note 5	25°C		75			75		Ω	
Ci	Input capacitance		25°C		1.4			1.4		pF	
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}$	25°C	70	90		70	90		dB	
CIVIRR			Full range	70			70				
ks∨s	Supply-voltage sensitivity	$V_{CC} = \pm 9$ V to $\pm 15$ V	25°C Full range		30	150		30	150	μV/V	
~572	$(\Delta V_{IO} / \Delta V_{CC})$					150			150	μν/ν	
IOS	Short-circuit output current		25°C		±25	±40		±25	±40	mA	
ICC	Supply current (each amplifier)	No load	25°C Full range		1.7	2.8 3.3		1.7	2.8 3.3	mA	
	Power dissipation		25°C		50	3.3 85		50	3.3 85		
PD	(each amplifier)	No load, $V_{O} = 0$	Full range		50	100		50	100	mW	
	Channel separation		25°C		120	100		120	0	dB	

### electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15 V$

<sup>†</sup> All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified.

<sup>‡</sup> Full range for uA747C is 0°C to 70°C and for uA747M is -55°C to 125°C.

\*On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

NOTE 5: This typical value applies only at frequencies above a few hundred hertz because of the effects of drift and thermal feedback.

# operating characteristics, V<sub>CC $\pm$ </sub> = $\pm$ 15 V, T<sub>A</sub> = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
tr	Rise time	1/2 = 20  m/2 By $= 2  k/2$ Cy $= 100  nE$ See Figure 1	0.3			μs
	Overshoot factor	$V_I = 20 \text{ mV}$ , $R_L = 2 \text{ k}\Omega$ , $C_L = 100 \text{ pF}$ , See Figure 1		5%		
SR	Slew rate at unity gain	$V_I = 10 \text{ mV}, R_L = 2 \text{ k}\Omega, C_L = 100 \text{ pF}, \text{ See Figure 1}$		0.5		V/µs



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### PARAMETER MEASUREMENT INFORMATION

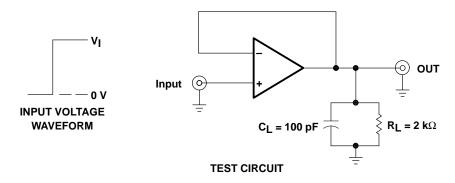


Figure 1. Rise Time, Overshoot, and Slew Rate

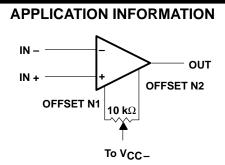
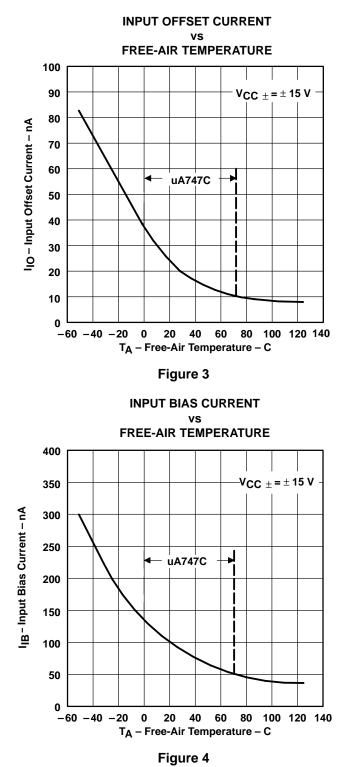


Figure 2. Input Offset Voltage Null Circuit



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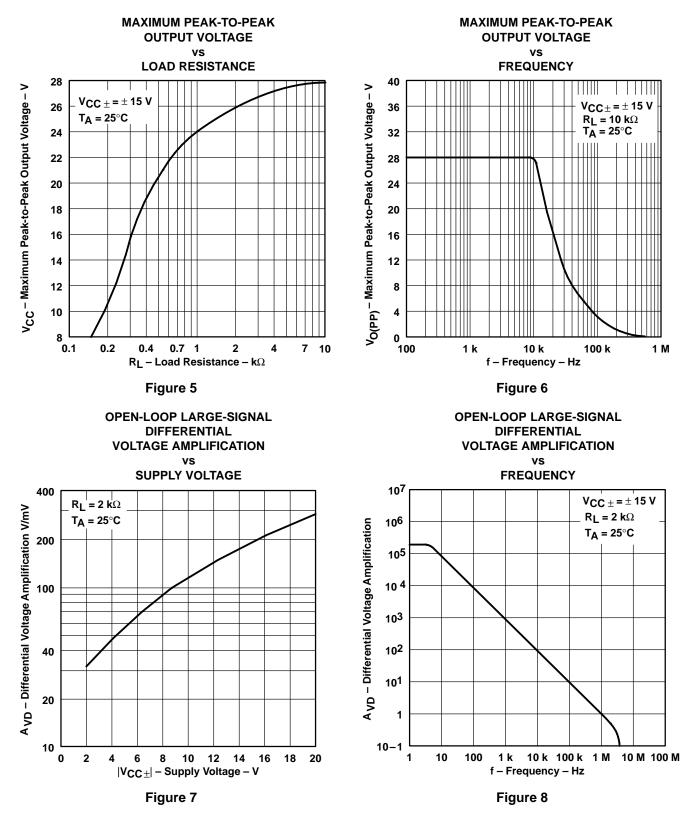
#### **TYPICAL CHARACTERISTICS<sup>†</sup>**



<sup>†</sup> Data at high and low temperatures are applicable only within the rated operating free-air temperature range of the particular devices.



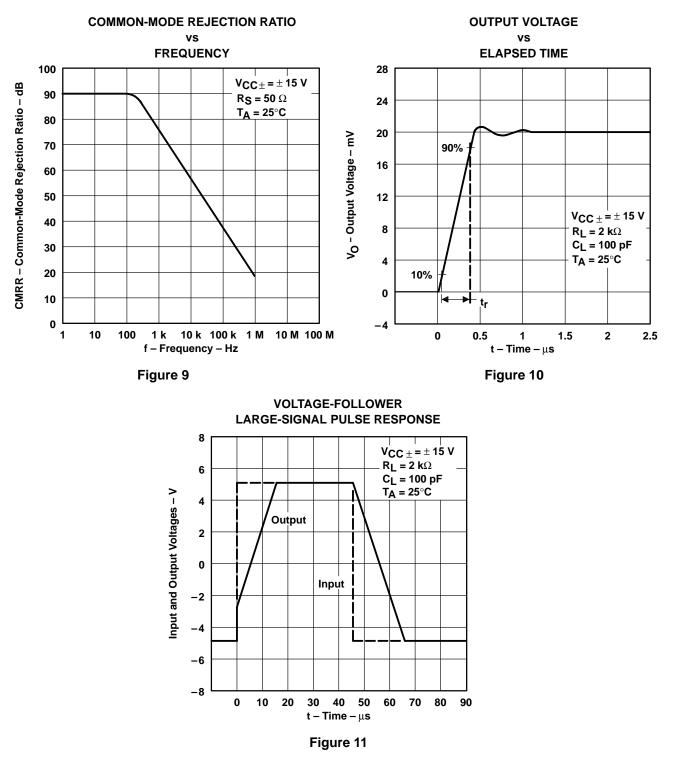
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#### **TYPICAL CHARACTERISTICS**



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#### **TYPICAL CHARACTERISTICS**



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